## NSN 5961-01-322-0511

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View Online at https://aerobasegroup.com/nsn/5961-01-322-0511

The Chimic at https://doi.org/1001/0001/01/022/0011
Internal Configuration:
Field effect
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-205ad
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 gate to source voltage and 90.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 3.5 gate to
source threshold voltage and 1.2 forward gate to source breakdown voltage
Current Rating Per Characteristic:
2.00 amperes all primaries of standard range and 10.00 microamperes zero-gate-voltage source current megawatts and 50.00
nanoamperes zero-gate-voltage source current watts and 2.00 amperes collector current, dc of standard range
Power Rating Per Characteristic:
6.25 watts any acceptable absolute
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiia: